-3A / -12V Bipolar transistor 2SB1713

Applications

Low frequency amplification, driver

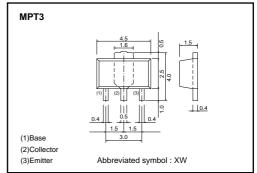
● Features

- 1) Collector current is high.
- 2) Low collector-emitter saturation voltage. (Typ. = -250mV, at Ic = -1.5A, IB = -30mA)

●Structure

PNP epitaxial planar silicon transistor

●External dimensions (Unit : mm)



● Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit	
Collector-base voltage		Vсво	-15	V	
Collector-emitter voltage		Vceo	-12	V	
Emitter-base voltage		Vево	-6	V	
Collector current	DC	lc	-3	А	
	Pulse	Іср	-6 *1		
Power dissipation		Pc	0.5 *2	W	
		PC	2 *3		
Junction temperature		Tj	150	°C	
Storage temperature		Tstg	-55 to +150	°C	

- *1 Pw=1ms, Pulsed.
 *2 Each terminal mounted on a recommended land.
 *3 Mounted on a 40×40×0.7mm ceramic board.

Packaging specifications

	Package	MPT3	
	Packaging type	Taping	
	Code	T100	
Part No.	Basic ordering unit (pieces)	1000	
2SB1713		0	

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions			
Collector-emitter breakdown voltage	BVceo	-12	_	_		Ic= -1mA			
Collector-base breakdown voltage	ВУсво	-15	_	_	V	Ic= -10μA			
Emitter-base breakdown voltage	ВVево	-6	_	_		I _E = -10μA			
Collector cut-off current	Ісво	_	_	-100	nA	Vcb= -15V			
Emitter cut-off current	ІЕВО	_	_	-100		V _{EB} = -6V			
Collector-emitter saturation voltage	VcE(sat) *	_	-120	-250	mV	Ic/I _B = -1.5A/ -30mA			
DC current gain	hfe	270	_	680	_	Vce= -2V, Ic= -500mA			
Transition frequency	f⊤	_	280	_	MHz	Vc= -2V, I==500mA , f=100MHz			
Collector output capacitance	Cob	_	30	_	pF	Vcb= -10V , IE=0mA , f=1MHz			

•Electrical characteristics curves

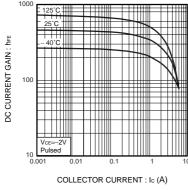


Fig1. DC current gain vs. collector current

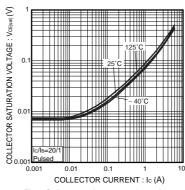


Fig.2 Collector-emitter saturation voltage vs. collector current

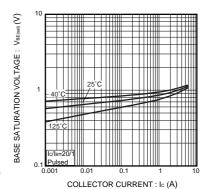


Fig.3 Base–emitter saturation voltage vs.collector current

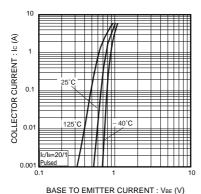


Fig.4 Grounded emitter propagation charactereistics

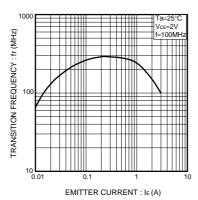
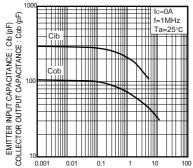


Fig.5 Gain bandwidth product vs. emitter current



EMITTER TO BASE VOLTAGE : VEB(V)
COLLECTOR TO BASE VOLTAGE : VCB(V)

Fig 6. Emitter input capacitance vs. emitter-base volatage Collector output capacitance vs. collector-base voltage

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